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June 10, 2003

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P.O. E	nissioner For Patents Box 1450 ndria, VA 22313-145	0									
Re:	Applicant(s): Harari et al. Assignee: SanDisk Corporation Title: Flash Eeprom System Application No.: 09/759,119 Examiner: Trong Phan Docket No.: SNDK.A06US5			Filing Date: Group Art Unit: Conf. No.:			January 11, 2001 2818 Unknown				
Dear S	Sir:								100		
Trans	(3) Fourth Volunta(4) Copy of U.S. P(5) Check for \$576No additional fee i	Postcard; al Letter (in duplicate ry Amendment (46 p atent No. 6,404,675; 6.00. s required. alculated as shown be	e); ages); and elow:			ation	1:				
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Fee for Petition for Extension of Time								S			
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\boxtimes	filing of the enclosed document(s) after all papers filed with this transmittal have been considered, an extension of time is hereby requested.										
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the U	by certify that this corresp nited States Postal Service mail in an envelope addres 30x 1450, Alexandria, VA	with sufficient postage a	s first Patents	Mic Pat	chael G. Clent Agent g. No. 46,0	leve					

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants:

Eliyahou Harari et al.

Assignee:

SanDisk Corporation

Title:

Flash EEPROM System

Application No.:

09/759,119

Filing Date:

January 11, 2001

Examiner:

Trong Phan

Group Art Unit:

2818

Docket No.:

SNDK.A06US5

Conf. No.:

Unknown

Certificate of Mailing Under 37 CFR 1.8

Signature

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

FOURTH VOLUNTARY AMENDMENT

Dear Sir:

Please amend the above referenced Application as follows:

In the Claims:

Please add the following new claims:

--107.(New) A non-volatile semiconductor memory device comprising:

a plurality of non-volatile memory cells each of which has a floating gate and a threshold voltage representing data of at least two bits, wherein electrons are capable of being injected into the floating gate, and wherein threshold voltages of the plurality of non-volatile memory cells are shiftable among at least three threshold levels which indicate mutually different programming states and which also differ from a threshold level indicating an erase state; and

Application No.: 09/759,119

Serial No.: 09/759,119

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